

FEATHER

^{4M} ^{4M(H)} **108-cell**

415W

alf-cut Mono Perc eight

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OUCT CERTIFICATES



Management Sys.

ISO 9001. y Management System

ISO 14001: ∠ onment Management System
ISO 45001: 201 ational Health and Safety





PERFORMANCE WARRANTY





Linear Performance Warranty







Light-Weight

Reduce roof loads, easy operation, lower installation cost



10BB Half-cut Cell Technology

New circuit design, lower internal current, lower Rs loss Ga dopped wafer, attenuation $<\!2\%$ (1st year) / 0.55% (Linear)



Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



Excellent Anti-PID Performance

2 times of industry standard Anti-PID test



IP68 Junction Box

High waterproof level

ELECTRICAL CHARACTERISTICS

395	294	400	298	405	302	410	306	415	310
30.85	28.8	31.05	29.0	31.24	29.2	31.43	29.3	31.64	29.6
12.81	10.23	12.89	10.30	12.97	10.36	13.05	10.42	13.13	10.48
36.75	34.6	37.00	34.8	37.25	35.1	37.50	35.3	37.75	35.5
13.69	11.04	13.78	11.11	13.86	11.17	13.94	11.24	14.02	11.30
20.20		20.50		20.70		21.00		21.30	

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MECHANICAL CHARACTERISTICS

Monocrystalline Silicon (10Busbar)
108pcs in series (6*18)
1722*1134*30mm (67.80*44.65*1.18inches)
16.2kg (35.72lbs.)
2.0mm AR Coating Tempered Glass
Anodized Aluminium Alloy
IP68, 3 Bypass Diodes
4mm² (IEC), 12AWG(UL) 300mm in Length or Customized Length
T01/LJQ-3-CSY/MC4/MC4-EV02

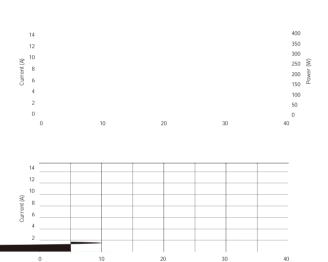
APPLICATION CONDITIONS

10001/13001/DC
-40°C~+85°C
25A
Class II

TEMPERATURE CHARACTERISTICS

-0.35%/°C
-0.26%/°C
+0.048%/°C
43±2°C

I-V CURVE



TECHNICAL DRAWINGS

Ightly and are not guaranteed. Due to ongoing innovation, R&D to make any adjustment to the information described herein at any asheet which shall be duly incorporated into the binding contract made to of the products described herein.